

FU-427SLD-F1M51/F1M52

1.3 μm LD MODULE WITH SINGLEMODE FIBER PIGTAIL

DESCRIPTION

Module type FU-427SLD-F1M5X has been developed for coupling a singlemode optical fiber and a 1.3 μm wavelength InGaAsP LD (Laser diode).

FU-427SLD-F1M5X is suitable to light source for measuring instruments.(especially, OTDR)

FEATURES

- High optical output power
- Emission wavelength is in 1.3 μm band

APPLICATION

OTDR

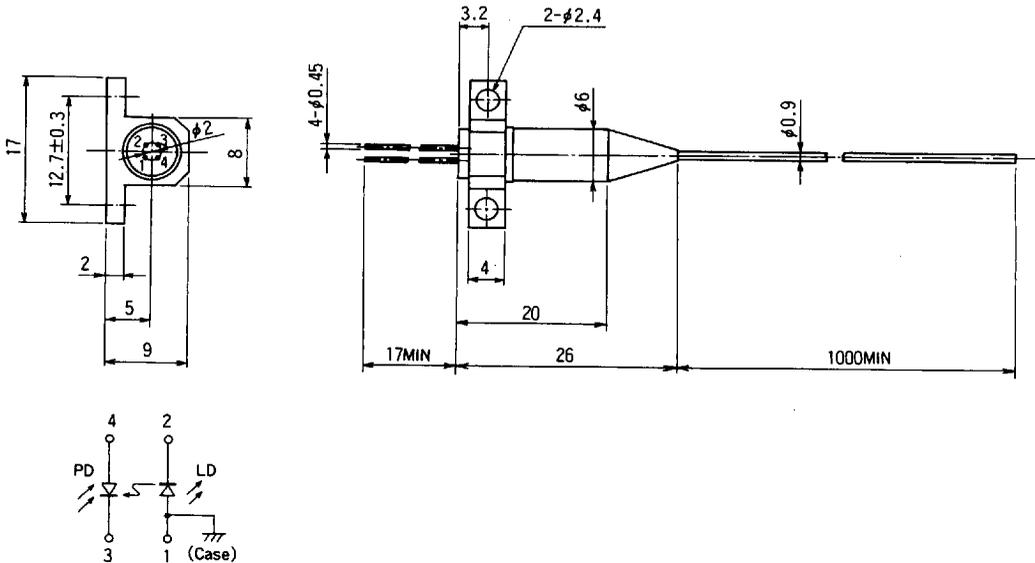
ABSOLUTE MAXIMUM RATINGS (Tc = 25 °C)

Parameter	Symbol	Conditions	Rating	Unit	
Laser diode	Reverse voltage	V _{RL}	-	2	V
	Forward current	I _{FL}	Pulse (Note 1)	250	mA
Photodiode for monitoring	Reverse voltage	V _{RD}	-	15	V
	Forward current	I _{FD}	-	2	mA
Operating case temperature	T _c	-	0~+60	°C	
Storage temperature	T _{stg}	-	-40~+70	°C	

Note 1. Pulse condition : Pulse width ≤ 10 μs, Duty ratio ≤ 1 %

OUTLINE DIAGRAM

(Unit : mm)



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CW CHARACTERISTICS

Parameter	Symbol	Test conditions	Limits						Unit
			FU-427SLD-F1M51			FU-427SLD-F1M52			
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Threshold current	I _{th}	CW, T _c = 25 °C	-	6	15	-	6	15	mA
Operating current	I _{OP}	CW, APC, P _f = 2mW, T _c = 25 °C	-	18	35	-	18	35	mA
Operating voltage	V _{OP}	CW, APC, P _f = 2mW, T _c = 25 °C	-	1.2	1.6	-	1.2	1.6	V
Central wavelength (Note 3)	λ _c	CW, APC, P _f = 2mW, T _c = 25 °C	1290	1305	1320	1280	1305	1330	nm
Spectral width (RMS) (Note 3)	Δλ	CW, APC, P _f = 2mW, T _c = 25 °C	-	1.2	4	-	1.2	4	nm
Rise and fall times	t _r , t _f	I _b = I _{th} , 10~90% T _c = 25 °C (Note 2)	-	0.4	1	-	0.4	1	ns
Tracking error (Note 4)	E _r	CW, APC, I _{mon} (P _f (25 °C) = 2mW), T _c = 0~60 °C	-	0.4	1.0	-	0.4	1.0	dB
Monitor current	I _{mon}	CW, P _f = 2mW, V _{RD} = 5V T _c = 25 °C	0.1	0.6	1.5	0.1	0.6	1.5	mA
Dark current (Photodiode)	I _D	V _{RD} = 5V T _c = 25 °C	-	0.1	1	-	0.1	1	μA

Note 2. I_b : Bias current (LD)

3. λ_c = (Σ(ai * λ_i)) / (Σai)

$$\Delta\lambda = (1/(\Sigma ai) * (\Sigma ai * (\lambda_i - \lambda_c)^2))^{1/2}$$

where ai ≥ ap × 0.01

ai : Relative intensity of laser spectral emission modes

ap : Peak of laser spectral emission modes

4. E_r = MAX | 10 * log(P_f(T_c) / P_f(25 °C)) |

PULSE CHARACTERISTICS

Parameter	Symbol	Test conditions	Limits						Unit
			FU-427SLD-F1M51			FU-427SLD-F1M52			
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Threshold current	I _{th}	Pulse, T _c = 25 °C	-	6	15	-	6	15	mA
Operating current	I _{OPP}	Pulse, T _c = 25 °C	-	150	200	-	150	200	mA
Operating voltage	V _{OPP}	Pulse, I _f = I _{OPP} T _c = 25 °C	-	-	3.5	-	-	3.5	V
Optical output power from fiber end	P _{FP}	Pulse, I _f = I _{OPP} T _c = 25 °C	20	-	-	20	-	-	mW
		Pulse, I _f = I _{OPP} T _c = 60 °C	15	-	-	15	-	-	
Central wavelength (Note 8)	λ _{CP}	Pulse, I _f = I _{OPP} T _c = 25 °C	1300	1310	1320	1290	1310	1330	nm
Spectral bandwidth (RMS) (Note 8)	Δλ _P	Pulse, I _f = I _{OPP} T _c = 25 °C	-	-	10	-	-	10	nm
Pulse droop (Note 9)	ΔP _{FP}	Pulse, I _f = I _{OPP} T _c = 25 °C	-	-	20	-	-	20	%
Rise and fall times	t _r , t _f	I _b = I _{th} , 10~90% T _c = 25 °C (Note 7)	-	0.5	2	-	0.5	2	ns

Note 5. Pulse condition : Pulse width ≤ 10 μs, Duty ratio ≤ 1 %

6. I_f : Forward current (LD)

7. I_b : Bias current (LD)

8. λ_{CP} = (Σ(ai * λ_i)) / (Σai)

$$\Delta\lambda_P = (1/(\Sigma ai) * (\Sigma ai * (\lambda_i - \lambda_c)^2))^{1/2}$$

where ai ≥ ap × 0.01

ai : Relative intensity of laser spectral emission modes

ap : Peak of laser spectral emission modes

9. ΔP_{FP} = (P_{F1} - P_{F2}) / P_{F1} * 100

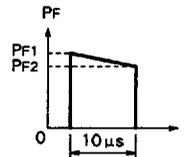


Fig.1



OPTICAL-FIBER SPECIFICATIONS

Parameter	Limits	Unit
Type	SM	-
Mode field dia.	10 ± 1	μm
Cladding dia.	125 ± 2	μm
Jacket dia.	0.9 typ.	mm

TYPICAL CHARACTERISTICS

